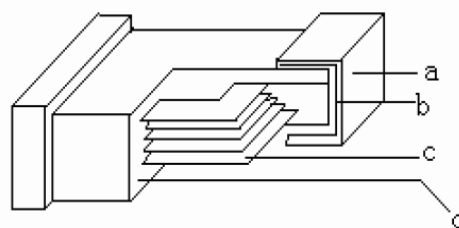
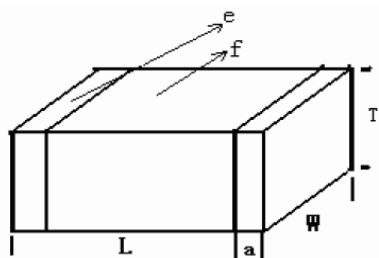


SPECIFICATION FOR APPROVAL

CUSTOMER		CUST P/N.	
ITEM	Chip Bead	Description	
Part No.	CB系列	DATE	2020.11.1

Dimension & Inner-configuration: 单位:mm (inch)



- a. 端电极 Terminal electrode
- b. 镀层 Ni/Sn plating
- c. 内电极 Inner electrode
- d. 瓷体 Body
- e. 端电极 Terminal electrode
- f. 瓷体 ferrite or ceramic

Size	L	W	T	a
100505N	1.0±0.15	0.5±0.15	0.5±0.15	0.25±0.1
160808N	1.6±0.2	0.8±0.2	0.8±0.2	0.3±0.2
201209N	2.0±0.2	1.2±0.2	0.9±0.2	0.5±0.3

Product Spec. Model

CBG 160808 N- 120

阻值 Impedance: $12 \times 10^1 = 120 \Omega$

Pb-free

尺寸 Dimensions: (L×W×T) (1.6×0.8×0.8mm)

产品类型 Product symbol:

CBG: 普通型磁珠 normal beads

CBW: 大电流磁珠 Power beads

CBM: 超大电流磁珠 Ultra-high Current beads

STORAGE TEMPERATURE RANGE-40 ~+125

OPERATING TEMPERATURE RANGE-40 ~+125

MINGSTAR ELECTRONIC CORP.

GRAPH

CUSTOMER:		Part No.	CBM100505		Test Q'ty:		PCS
CUST P/N.		Description:	Superhigh current Chip Bead		Date:	2020.11.1	

客戶P/N	Item	Impedance		DC Recistance	IDC	Test Frequency (MHz/V)
		Ω	Tol(公差)	Ω(Max)	mA(Max)	
	CBM100505N-070	7.0	0~11Ω	0.02	2000	100MHz/50mV
	CBM100505N-090	9.0	5~13Ω	0.02	2000	100MHz/50mV
	CBM100505N-110	11.0	7~15Ω	0.02	2000	100MHz/50mV
	CBM100505N-150	15.0	9~21Ω	0.02	2000	100MHz/50mV
	CBM100505N-190	19.0	12~25Ω	0.035	1700	100MHz/50mV
	CBM100505N-260	26.0	±25%	0.06	1500	100MHz/50mV
	CBM100505N-300	30.0	±25%	0.06	1500	100MHz/50mV
	CBM100505N-600	60.0	±25%	0.10	1300	100MHz/50mV
	CBM100505N-101	100.0	±25%	0.15	1000	100MHz/50mV
	CBM100505N-121	120.0	±25%	0.15	1000	100MHz/50mV
	CBM100505N-151	150.0	±25%	0.20	700	100MHz/50mV
	CBM100505N-201	200.0	±25%	0.25	700	100MHz/50mV
	CBM100505N-221	220.0	±25%	0.28	700	100MHz/50mV
	CBM100505N-301	300.0	±25%	0.30	600	100MHz/50mV
	CBM100505N-501	500.0	±25%	0.40	500	100MHz/50mV
	CBM100505N-601	600.0	±25%	0.50	500	100MHz/50mV
	CBM100505N-801	800.0	±25%	0.65	300	100MHz/50mV
	CBM100505N-102	1000.0	±25%	0.65	300	100MHz/50mV

	APPROVED	CHECKED	DRAWN BY

MINGSTAR ELECTRONIC CORP.

GRAPH

CUSTOMER:		Part No.	CBM160808		Test Q'ty:		PCS
CUST P/N.		Description:	Superhigh current Chip Bead		Date:	2020.11.1	

客戶P/N	Item	Impedance		DC Recistance	IDC	Test Frequency (MHz/V)
		Ω	Tol(公差)	Ω(Max)	mA(Max)	
	CBM160808N-070	7.0	0~11Ω	0.01	6000	100MHz/50mV
	CBM160808N-090	9.0	5~13Ω	0.01	6000	100MHz/50mV
	CBM160808N-110	11.0	7~15Ω	0.01	6000	100MHz/50mV
	CBM160808N-150	15.0	9~21Ω	0.01	6000	100MHz/50mV
	CBM160808N-190	19.0	12~25Ω	0.01	6000	100MHz/50mV
	CBM160808N-260	26.0	±25%	0.03	5000	100MHz/50mV
	CBM160808N-300	30.0	±25%	0.03	4000	100MHz/50mV
	CBM160808N-500	50.0	±25%	0.04	3000	100MHz/50mV
	CBM160808N-600	60.0	±25%	0.04	3000	100MHz/50mV
	CBM160808N-700	70.0	±25%	0.06	2500	100MHz/50mV
	CBM160808N-750	75.0	±25%	0.06	2500	100MHz/50mV
	CBM160808N-800	80.0	±25%	0.06	2500	100MHz/50mV
	CBM160808N-101	100.0	±25%	0.06	2500	100MHz/50mV
	CBM160808N-121	120.0	±25%	0.065	2000	100MHz/50mV
	CBM160808N-151	150.0	±25%	0.07	1500	100MHz/50mV
	CBM160808N-181	180.0	±25%	0.09	1500	100MHz/50mV
	CBM160808N-221	220.0	±25%	0.12	1500	100MHz/50mV
	CBM160808N-301	300.0	±25%	0.15	1500	100MHz/50mV
	CBM160808N-331	330.0	±25%	0.18	1300	100MHz/50mV
	CBM160808N-501	500.0	±25%	0.18	1300	100MHz/50mV
	CBM160808N-601	600.0	±25%	0.18	1300	100MHz/50mV
	CBM160808N-801	800.0	±25%	0.30	800	100MHz/50mV
	CBM160808N-102	1000.0	±25%	0.35	700	100MHz/50mV

	APPROVED	CHECKED	DRAWN BY

MINGSTAR ELECTRONIC CORP.

GRAPH

CUSTOMER:		Part No.	CBM201209		Test Q'ty:		PCS
CUST P/N.		Description:	Superhigh current Chip Bead		Date:	2020.11.1	

客戶P/N	Item	Impedance		DC Resistance	IDC	Test Frequency (MHz/V)
		Ω	Tol(公差)	Ω(Max)	mA(Max)	
	CBM201209N-070	7.0	0~11Ω	0.01	6000	100MHz/50mV
	CBM201209N-090	9.0	5~13Ω	0.01	6000	100MHz/50mV
	CBM201209N-110	11.0	7~15Ω	0.01	6000	100MHz/50mV
	CBM201209N-150	15.0	9~21Ω	0.01	6000	100MHz/50mV
	CBM201209N-190	19.0	12~25Ω	0.01	6000	100MHz/50mV
	CBM201209N-300	30.0	±25%	0.01	6000	100MHz/50mV
	CBM201209N-500	50.0	±25%	0.03	4000	100MHz/50mV
	CBM201209N-600	60.0	±25%	0.03	4000	100MHz/50mV
	CBM201209N-700	70.0	±25%	0.04	4000	100MHz/50mV
	CBM201209N-800	80.0	±25%	0.04	4000	100MHz/50mV
	CBM201209N-101	100.0	±25%	0.045	4000	100MHz/50mV
	CBM201209N-121	120.0	±25%	0.045	4000	100MHz/50mV
	CBM201209N-151	150.0	±25%	0.07	3000	100MHz/50mV
	CBM201209N-181	180.0	±25%	0.07	3000	100MHz/50mV
	CBM201209N-221	220.0	±25%	0.07	3000	100MHz/50mV
	CBM201209N-301	300.0	±25%	0.08	2500	100MHz/50mV
	CBM201209N-501	500.0	±25%	0.09	2500	100MHz/50mV
	CBM201209N-601	600.0	±25%	0.10	2000	100MHz/50mV
	CBM201209N-102	1000.0	±25%	0.12	1500	100MHz/50mV

	APPROVED	CHECKED	DRAWN BY

MINGSTAR ELECTRONIC CORP.

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for [Ferrite Beads](#) category:

Click to view products by [MINGSTAR](#) manufacturer:

Other Similar products are found below :

[CZB1JGTTD152P](#) [CZB2AFTTD800P](#) [CZB2AGTTD121P](#) [PE-0402FB121ST](#) [AB 3X2X3SM](#) [NCB0603R301TR050F](#) [CZB2BFTTE301P](#)
[CZB2BFTTE601P](#) [4221R-1](#) [EMI0805R-600](#) [NCB0805A102TR040F](#) [EMI0805R-220](#) [WLBD1005HCU330TL](#) [WQBD1608HCU121TH](#)
[WLBD1608K2U252TB](#) [WLBD1608K2U800TP](#) [BBPY00160808301Y00](#) [BBPY00100505102Y00](#) [BBNQ00100505121Y00](#)
[BBPY00160808121Y00](#) [BBFY00100505221YHP](#) [ABPY00100505601Y00](#) [BBPY00201209101Y00](#) [ABPY00201209301Y00](#)
[ABPY00160808100Y00](#) [BBPY00160808601Y00](#) [BBPY00201209500Y00](#) [BBGK00160808121Y00](#) [BBPY00160808102Y00](#)
[ABM160808U301T](#) [BBPY00201209100Y00](#) [BBPY00100505100Y00](#) [BBPY00160808101Y00](#) [ABUP00100505600Y00](#)
[ABPY00321611121Y00](#) [ABPY00160808102Y00](#) [ABPY00160808221Y00](#) [BMC2AY0300AG](#) [BMC2AY0060AG](#) [BMC2AY0600AN](#)
[BMC2AY0220AN](#) [LLMCC201208T420RG](#) [LAMGL160808T102RD](#) [BMC2AY0120AN](#) [2176487-2](#) [2176486-4](#) [BMC2AY1000AN](#)
[LLMGA160808T601RG](#) [2176487-1](#) [LLMCC201208T250NG](#)